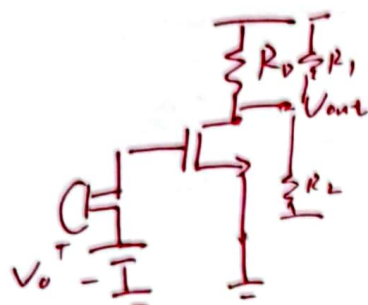




## Simplifications



$$\lambda = 0.$$

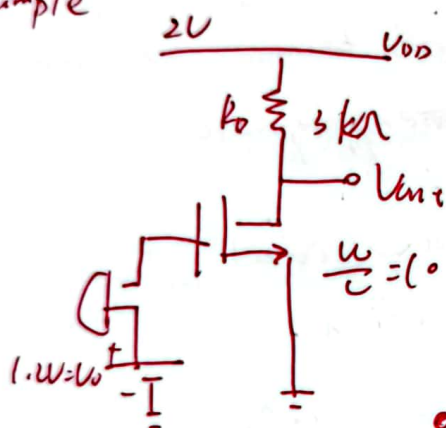
$A_v = -g_m$  (total resistance tied from drain to ac ground)

这里也假设在小信号模型中， $V_{bias}$ 和GND都为GND。

$$\therefore \text{for example } A_v = -g_m (R_D \parallel R_L \parallel R_L)$$

Common source  $\Rightarrow$   $V_{in} : V_{GS}$   
 $V_{out} : V_{DS}$

Example



First assume that it's in sat zone  
 $\Rightarrow$  calculate out and check the zone.

if we want to double the gain.

• Try doubling  $R_D$ ?  $[R_D \uparrow \quad V_{DS} \downarrow \text{ not in sat}]$

(we always want an amplifier working in sat).

(sat means larger  $I_D$ , larger  $A_v$  &  $C_{mac}$ )

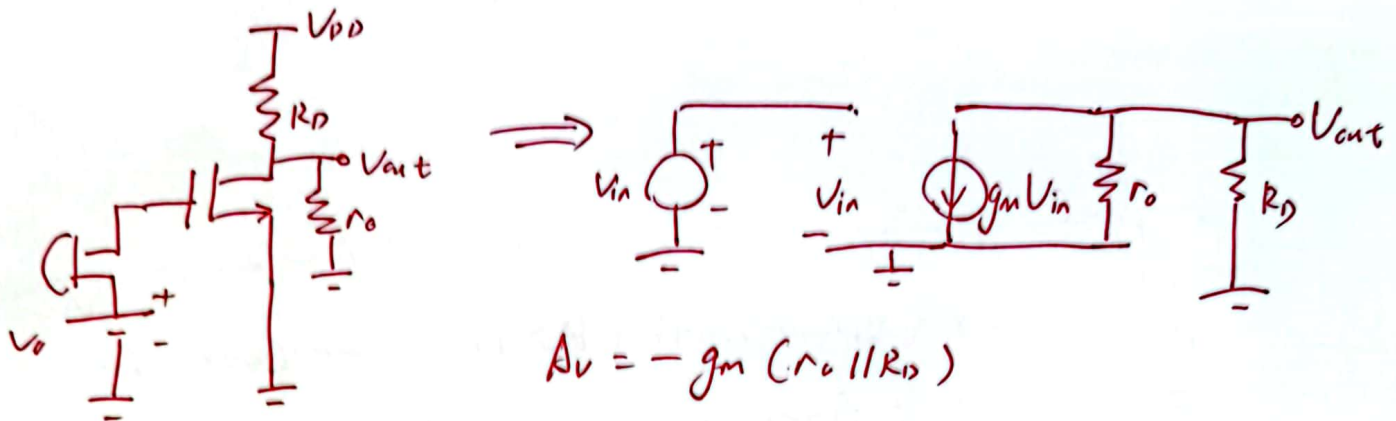
but in dc, ~~larger~~ larger  $I_D$  means ~~more~~  $I_D$  may out of sat.] we want the lower biasing

• Try increasing  $g_m = \sqrt{2\mu_n C_{ox} \frac{W}{L} I_D}$  but  $I_D$  higher supply of  $I_D$ ?  $I_D \propto (V_{GS} - V_T)^2$   $\frac{W}{L} \uparrow$ ?

if  $\frac{W}{L}$  becomes sufficiently large,

$$g_m \approx \frac{I_D}{1.5V_T} \rightarrow V_T = 26mV = \frac{kT}{q}$$

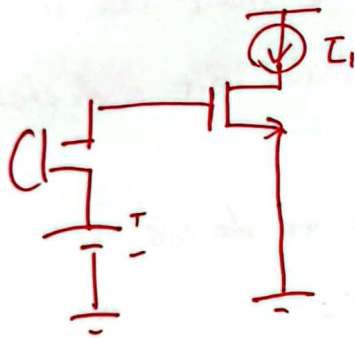
## Inclusion of Channel-Length Mod.



We want the largest  $A_v$ , means the largest  $R_D$ .

but the circuit cannot be open, because we need bias.

So, a current source is ~~appropriate~~ appropriate.



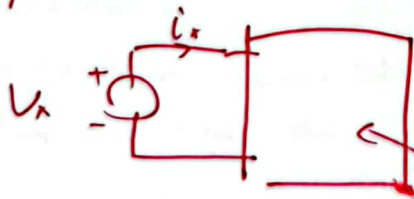
$I_1$  is const & ideal.

Saturation

Now  $A_v = -g_m r_o$ , intrinsic gain of  $M_0$   
usually = 50/10.

## Concept of Port Impedance

Input Impedance



set all independent sources to zero.

$$R_{in} = \frac{V_x}{i_x}$$

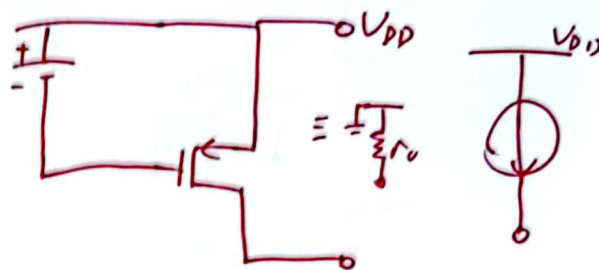
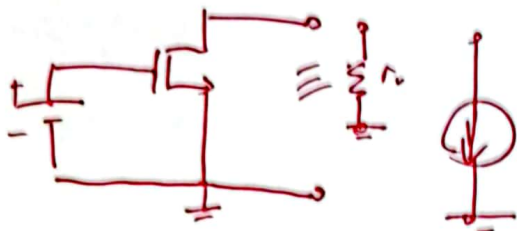
output ~~impedance~~ impedances



输入阻抗.



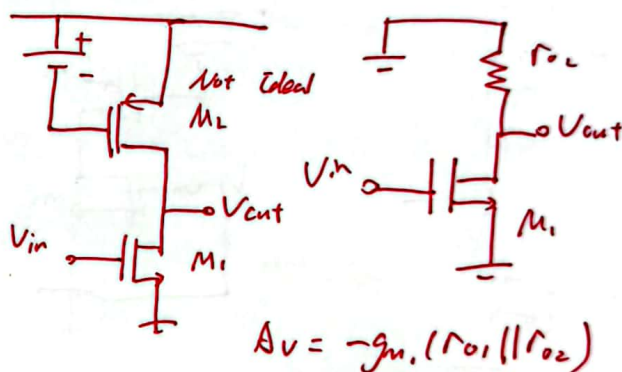
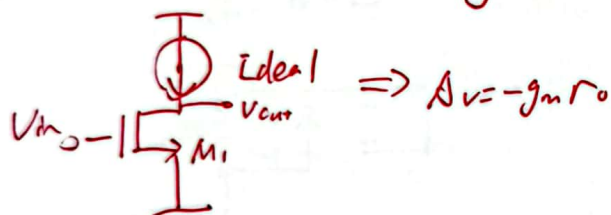
Let's build a current source:



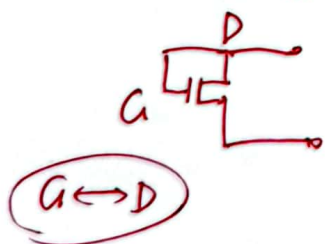
if a MOS is working as a current source, we can refer it as a  $r_o$ . ( $\lambda > 0$ )

$\lambda = 0 \Rightarrow$  open.

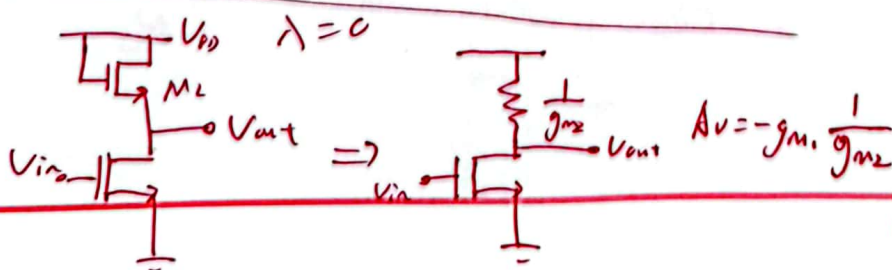
Common-Source Stage with Current-Source Load



Diode-Connected Device



$$\begin{cases} v_i = v_x \\ v_{gs} = \frac{v_x}{r_o} + g_m v_i \end{cases} \Rightarrow \frac{v_x}{v_{gs}} = r_o \parallel \frac{1}{g_m} \approx \frac{1}{g_m} \quad \text{if } \frac{1}{g_m} \ll r_o$$

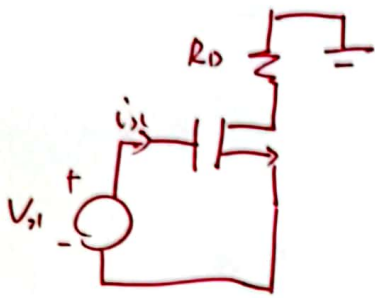


Common-Source Stage with Diode-Connected Load  
中国·杭州 HANGZHOU CHINA

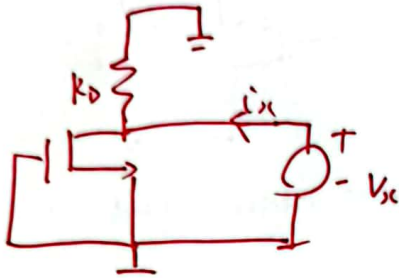


# Input and Output Impedances.

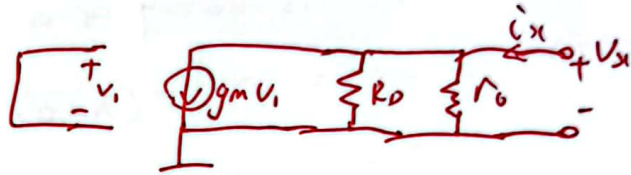
电压源



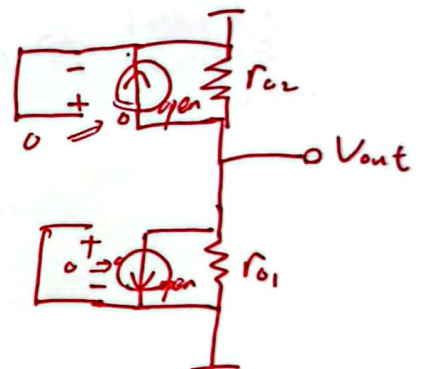
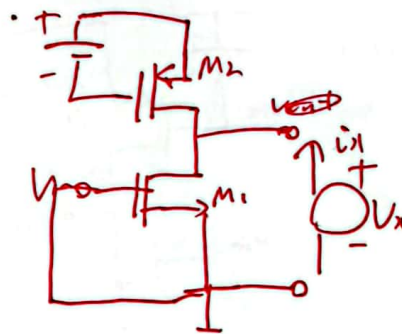
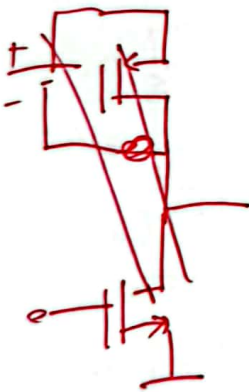
$$\text{input imp.} = \frac{V_x}{i_x} = \infty \quad (\text{at low frequencies})$$



$$\text{output imp.} = \frac{V_x}{i_x} = R_D \parallel r_o$$

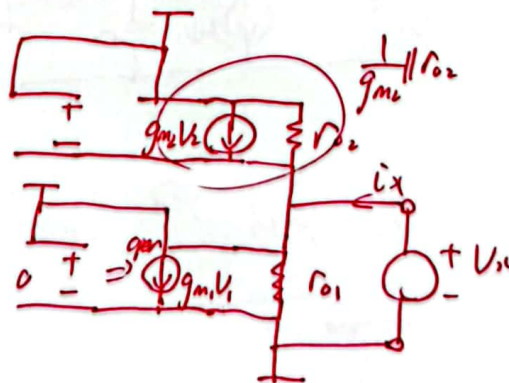


电压源



$$\frac{V_x}{i_x} = r_{o2} \parallel r_{o1}$$

二极管



$$\frac{V_x}{i_x} = \left( \frac{1}{g_{m2}} \parallel r_{o2} \right) \parallel r_{o1}$$